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We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## **KSK596**

## **Capacitor Microphone Applications**

- Especially Suited for use in Audio, Telephone Capacitor Microphones
- Excellent Voltage Characteristic
- Excellent Transient Characteristic



1. Source 2. Gate 3. Drain

## Si N-channel Junction FET

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{GDO}$	Gate-Drain Voltage	-20	V
I <sub>G</sub>	Gate Current	10	mA
I <sub>D</sub>	Drain Current	1	mA
P <sub>D</sub>	Power Dissipation	100	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

# **Electrical Characteristics** $T_a=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>GDO</sub>	Gate-Drain Breakdown Voltage	I <sub>G</sub> = -100uA	-20			V
V <sub>GS</sub> (off)	Gate-Source Cut-off Voltage	$V_{DS}=5V$ , $I_{D}=1\mu A$		-0.6	-1.5	V
I <sub>DSS</sub>	Drain Current	$V_{DS}=5V, V_{GS}=0$	100		350	μΑ
IY <sub>FS</sub> I	Forward Transfer Admittance	V <sub>DS</sub> =5V, V <sub>GS</sub> =0, f=1MHz	0.4	1.2		ms
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> =5V, V <sub>GS</sub> =0, f=1MHz		3.5		pF
C <sub>rss</sub>	Output Capacitance	V <sub>DS</sub> =5V, V <sub>GS</sub> =0, f=1MHz		0.65		pF

# I<sub>DSS</sub> Classification

Classification	Α	В	С	
I <sub>DSS</sub> (μA)	100 ~ 170	150 ~ 240	210 ~ 350	

# **Typical Characteristics**

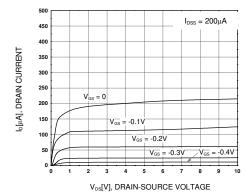


Figure 1.  $I_D$ - $V_{DS}$ 

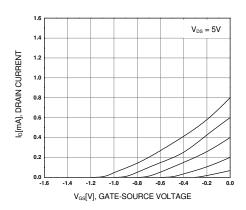


Figure 3.  $I_D$ - $V_{GS}$ 

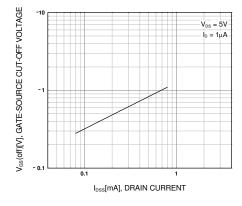


Figure 5.  $V_{GS}(off)$ - $I_{DSS}$ 

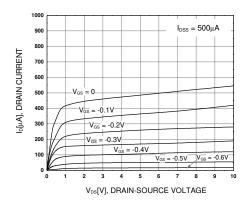


Figure 2.  $I_D$ - $V_{DS}$ 

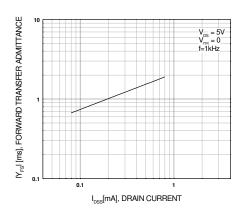


Figure 4. |yFS|-I<sub>DSS</sub>

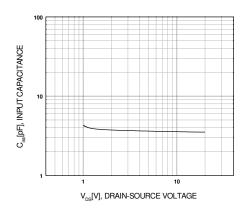


Figure 6.  $C_{ISS}$ - $V_{DS}$ 

# Typical Characteristics (Continued)

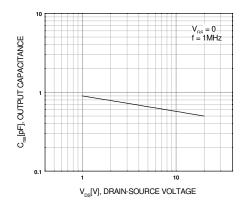


Figure 7.  $C_{RSS}$ - $V_{DS}$ 

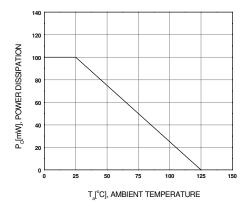
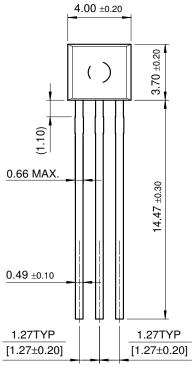
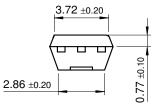


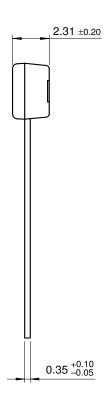
Figure 8. P<sub>D</sub>-T<sub>A</sub>

# **Package Dimensions**

**TO-92S** 







Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench <sup>®</sup>	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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E <sup>2</sup> CMOS <sup>TM</sup>	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I <sup>2</sup> C <sup>TM</sup>	OCXTM	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franc	hise™	OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	VCX™
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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Rev. I1

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Datasheet Identification	Product Status	Definition
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